

# 20 V, 6.6 A PNP low V<sub>CEsat</sub> (BISS) transistor Rev. 01 — 31 March 2010

Product data sheet

#### **Product profile** 1.

### **1.1 General description**

PNP low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor in a SOT223 (SC-73) medium power Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4021NZ.

### 1.2 Features and benefits

- Very low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- High energy efficiency due to less heat generation
- AEC-Q101 qualified
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

#### 1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

### 1.4 Quick reference data

#### Table 1. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-6.6	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	-	-20	A
R <sub>CEsat</sub>	collector-emitter saturation resistance	l <sub>C</sub> = -6 A; l <sub>B</sub> = -600 mA	<u>[1]</u> _	22	33	mΩ

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

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### 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline G	raphic symbol
1	base		
2	collector		2, 4
3	emitter		1
4	collector		3
			sym028

### 3. Ordering information

Table 3.         Ordering information						
Type number	Package	ge				
	Name	Description	Version			
PBSS4021PZ	SC-73	plastic surface-mounted package with increased heat sink; 4 leads	SOT223			

### 4. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS4021PZ	PB4021PZ

### 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			-		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-20	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-20	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current		-	-6.6	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	-20	A
I <sub>B</sub>	base current		-	-1	А

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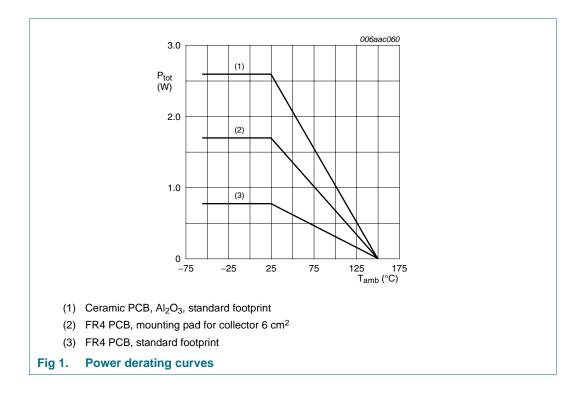
Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub> total power dissipat	total power dissipation	bation $T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	770	mW
			[2] _	1700	mW
			[3] _	2600	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
Г <sub>stq</sub>	storage temperature		-65	+150	°C

 Table 5.
 Limiting values ...continued

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB,  $AI_2O_3$ , standard footprint.



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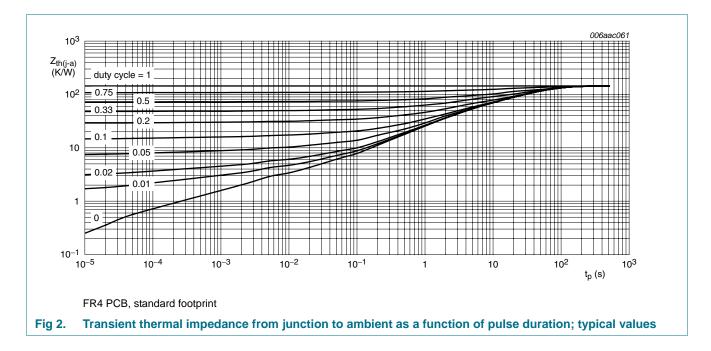
### 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
uii(j-a)	thermal resistance from	in free air	<u>[1]</u> _	-	160	K/W
	junction to ambient		[2] _	-	75	K/W
			<u>[3]</u> _	-	50	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	11	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

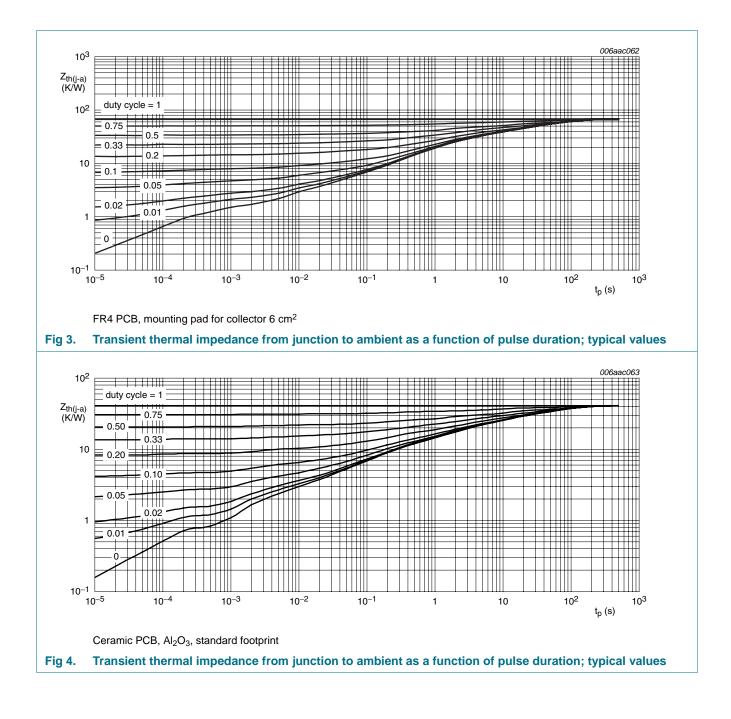
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB,  $AI_2O_3$ , standard footprint.



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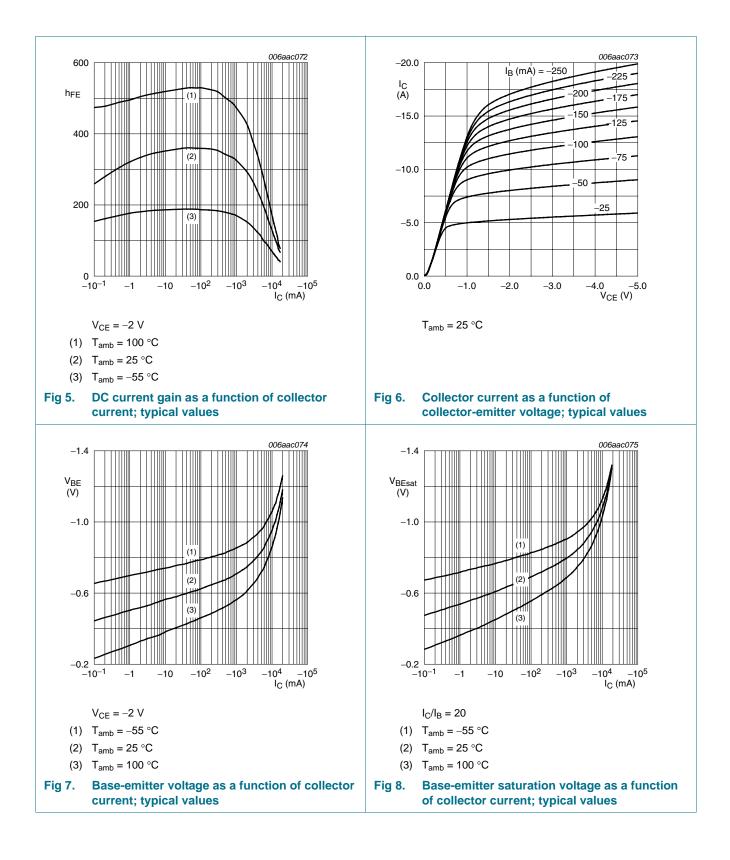
### 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = -20 \text{ V}; \text{ I}_E = 0 \text{ A}; \\ T_j = 150 \ ^\circ\text{C} \end{array}$		-	-	-55	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE} = -16 \text{ V}; \text{ V}_{BE} = 0 \text{ V}$		-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-100	nA
h <sub>FE</sub>	DC current gain		[1]				
		$V_{CE} = -2 V;$ $I_{C} = -500 \text{ mA}$		250	400	-	
		$V_{CE}$ = -2 V; $I_C$ = -1 A		250	400	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}$		200	350	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -4 \text{ A}$		150	250	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -7 \text{ A}$		100	180	-	
V <sub>CEsat</sub> collector-emitter			[1]				
	saturation voltage	$I_{C} = -1 \text{ A}; I_{B} = -50 \text{ mA}$		-	-31	-50	mV
		$I_{C}$ = -1 A; $I_{B}$ = -10 mA		-	-53	-80	mV
		$I_{C} = -2 \text{ A}; I_{B} = -40 \text{ mA}$		-	-66	-100	mV
		$I_{C} = -4 \text{ A}; I_{B} = -200 \text{ mA}$		-	-95	-140	mV
		$I_C = -4 \text{ A}; I_B = -40 \text{ mA}$		-	-150	-225	mV
		$I_{C} = -7$ A; $I_{B} = -350$ mA		-	-160	-240	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{\rm C} = -6$ A; $I_{\rm B} = -600$ mA	<u>[1]</u>	-	22	33	mΩ
V <sub>BEsat</sub>	base-emitter	$I_C = -1$ A; $I_B = -50$ mA	[1]	-	-0.79	-0.9	V
	saturation voltage	$I_{C} = -4 \text{ A}; I_{B} = -400 \text{ mA}$	[1]	-	-0.94	-1.05	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}$	[1]	-	-0.73	-0.85	V
t <sub>d</sub>	delay time	$V_{CC} = -12.5 V;$		-	55	-	ns
t <sub>r</sub>	rise time	$I_{C} = -1 \text{ A}; I_{Bon} = -0.05 \text{ A};$ $I_{Boff} = 0.05 \text{ A}$		-	60	-	ns
t <sub>on</sub>	turn-on time	IROII - 0.00 V		-	115	-	ns
t <sub>s</sub>	storage time			-	400	-	ns
t <sub>f</sub>	fall time			-	110	-	ns
t <sub>off</sub>	turn-off time			-	510	-	ns
f <sub>T</sub>	transition frequency	$V_{CE} = -10 \text{ V};$ $I_{C} = -100 \text{ mA};$ f = 100  MHz		-	85	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A}; \text{ f} = 1 \text{ MHz}$		-	125	-	pF

 $\label{eq:point} \begin{tabular}{ll} \begin{$ 

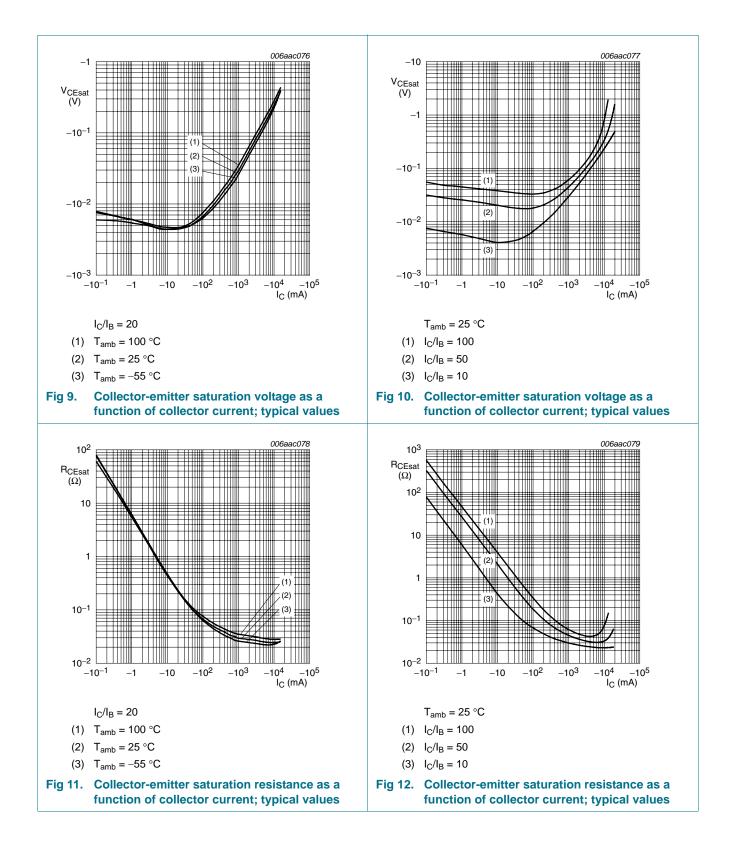
# PBSS4021PZ

#### 20 V, 6.6 A PNP low V<sub>CEsat</sub> (BISS) transistor



### PBSS4021PZ

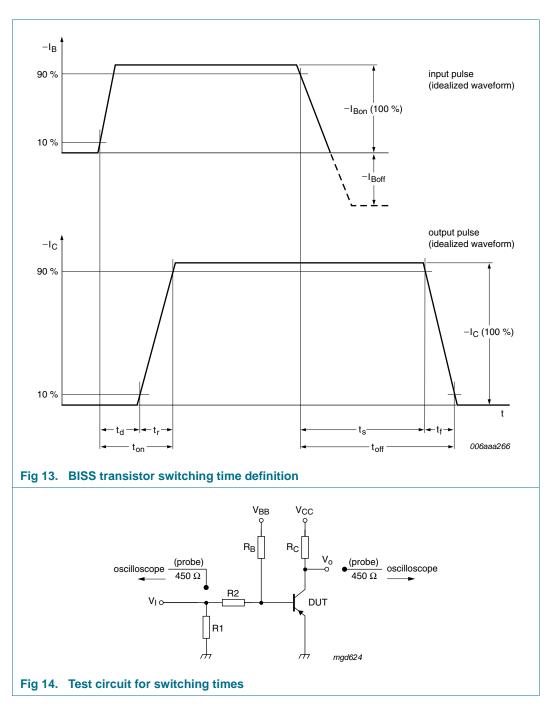
#### 20 V, 6.6 A PNP low V<sub>CEsat</sub> (BISS) transistor



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### 8. Test information

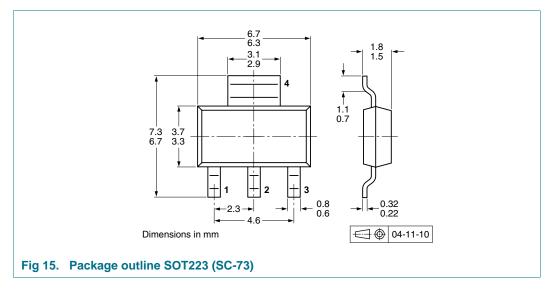


### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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### 9. Package outline



### **10. Packing information**

#### Table 8. Packing methods

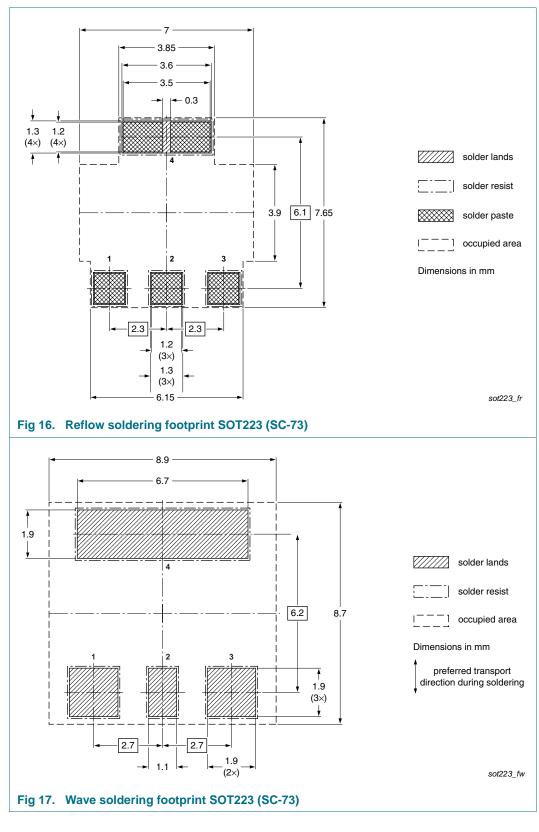
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			1000	4000
PBSS4021PZ	SOT223	8 mm pitch, 12 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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### **11. Soldering**



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### **12. Revision history**

Table 9. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4021PZ_1	20100331	Product data sheet	-	-

#### 20 V, 6.6 A PNP low V<sub>CEsat</sub> (BISS) transistor

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nexperia.com">salesaddresses@nexperia.com</a>

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